



SANYO Semiconductors

DATA SHEET

DA573S6 — Silicon Diffused Junction Type Diode ESD Protection Diode

Features

- Contact discharge 30kV guarantee (IEC61000-4-2).
- 6-pin package containing 5 devices.
- Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V _R	I _R =1mA	6.0		7.7	V
Reverse Current	I _R	V _R =5V			1	μA
Interterminal Capacitance	C	V _R =0V, f=1MHz		30		pF
ESD Discharge	V _{ESD}	C=150pF, R=330Ω, Contact discharge (IEC61000-4-2)	30			kV

(Note) Electrical characteristics are for one diode.

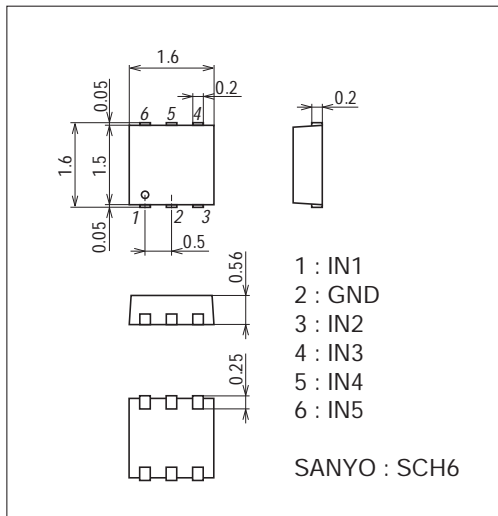
Marking : 4C

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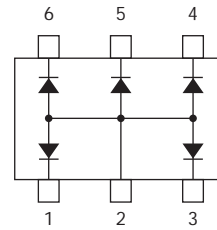
Package Dimensions

unit : mm (typ)

7028-011

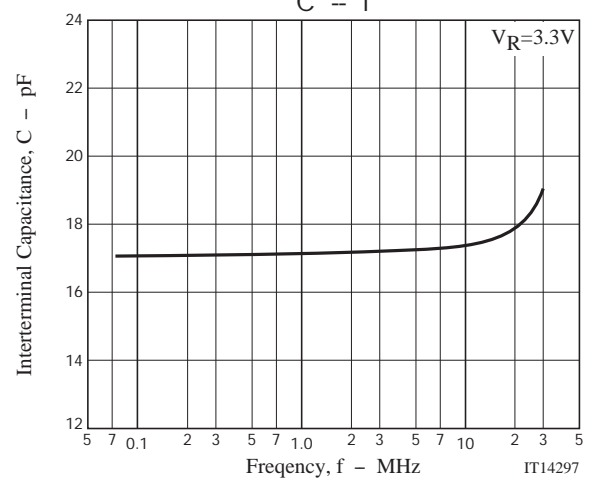
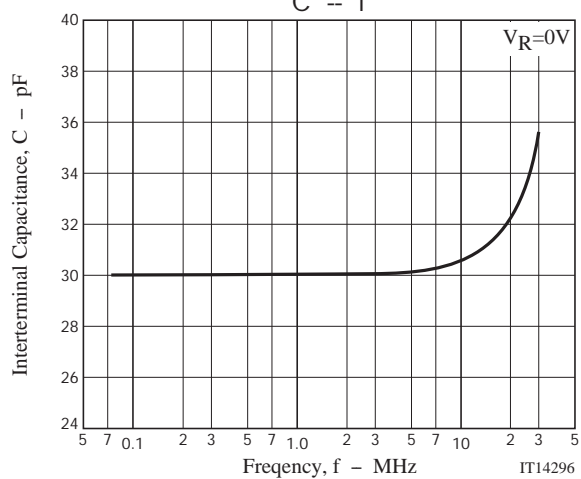
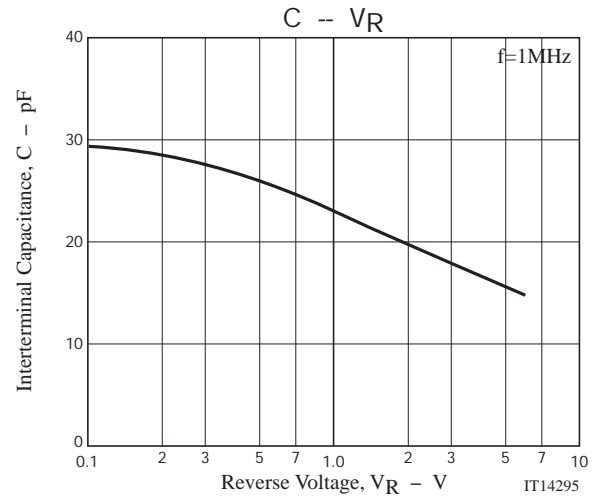
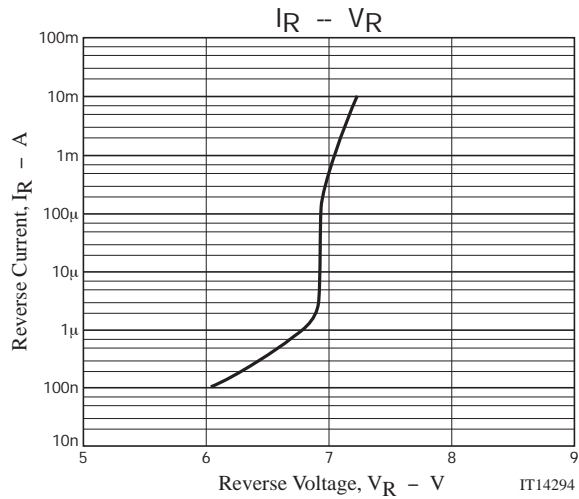


Electrical Connection

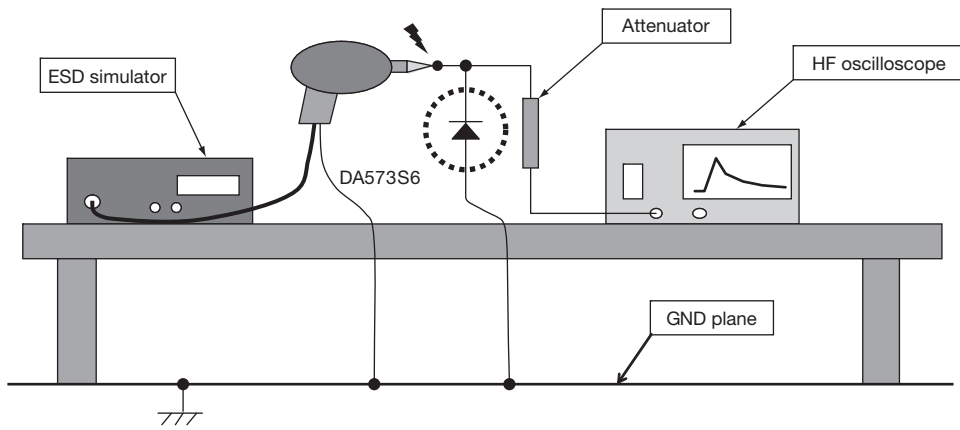
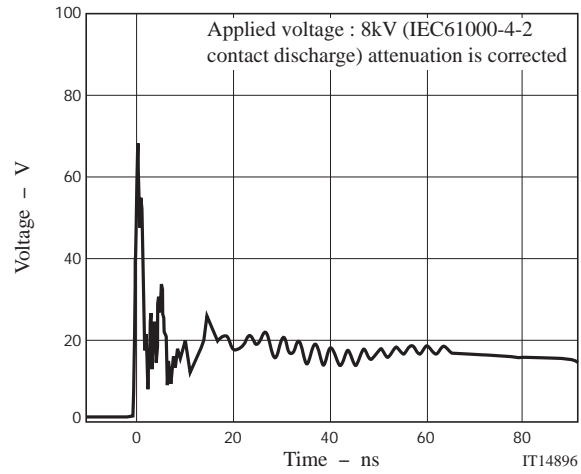


1 : IN1
2 : GND
3 : IN2
4 : IN3
5 : IN4
6 : IN5

Top view



ESD Suppressing Voltage Waveform (for reference)



Evaluation method (IEC61000-4-2 contact discharge)

IT14772

Note: In the above circuit, the oscilloscope may be destroyed when 8kV is applied without protection device.
The ESD suppressing voltage waveform shown above is taken with one unit diode.

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